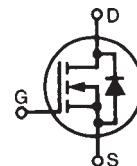


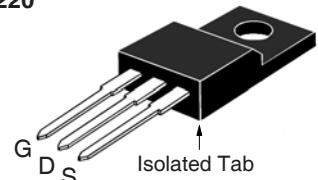
**X3-Class HiPerFET™  
Power MOSFET**
**IXFP36N20X3M****(Electrically Isolated Tab)**

N-Channel Enhancement Mode



**V<sub>DSS</sub>** = 200V  
**I<sub>D25</sub>** = 36A  
**R<sub>DS(on)</sub>** ≤ 45mΩ

OVERMOLDED  
TO-220



G = Gate      D = Drain  
 S = Source

Symbol	Test Conditions	Maximum Ratings	
V <sub>DSS</sub>	T <sub>J</sub> = 25°C to 150°C	200	V
V <sub>DGR</sub>	T <sub>J</sub> = 25°C to 150°C, R <sub>GS</sub> = 1MΩ	200	V
V <sub>GSS</sub>	Continuous	±20	V
V <sub>GSM</sub>	Transient	±30	V
I <sub>D25</sub>	T <sub>C</sub> = 25°C, Limited by T <sub>JM</sub>	36	A
I <sub>DM</sub>	T <sub>C</sub> = 25°C, Pulse Width Limited by T <sub>JM</sub>	50	A
I <sub>A</sub>	T <sub>C</sub> = 25°C	18	A
E <sub>AS</sub>	T <sub>C</sub> = 25°C	300	mJ
dv/dt	I <sub>S</sub> ≤ I <sub>DM</sub> , V <sub>DD</sub> ≤ V <sub>DSS</sub> , T <sub>J</sub> ≤ 150°C	20	V/ns
P <sub>D</sub>	T <sub>C</sub> = 25°C	36	W
T <sub>J</sub>		-55 ... +150	°C
T <sub>JM</sub>		150	°C
T <sub>stg</sub>		-55 ... +150	°C
T <sub>L</sub>	Maximum Lead Temperature for Soldering	300	°C
T <sub>SOLD</sub>	1.6 mm (0.062in.) from Case for 10s	260	°C
V <sub>ISOL</sub>	50/60 Hz, 1 Minute	2500	V~
M <sub>d</sub>	Mounting Torque	1.13 / 10	Nm/lb.in
Weight		2.5	g

Symbol	Test Conditions (T <sub>J</sub> = 25°C, Unless Otherwise Specified)	Characteristic Values		
		Min.	Typ.	Max.
BV <sub>DSS</sub>	V <sub>GS</sub> = 0V, I <sub>D</sub> = 250μA	200		V
V <sub>GS(th)</sub>	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 500μA	2.5		4.5 V
I <sub>GSS</sub>	V <sub>GS</sub> = ±20V, V <sub>DS</sub> = 0V			±100 nA
I <sub>DSS</sub>	V <sub>DS</sub> = V <sub>DSS</sub> , V <sub>GS</sub> = 0V T <sub>J</sub> = 125°C			5 μA 100 μA
R <sub>DS(on)</sub>	V <sub>GS</sub> = 10V, I <sub>D</sub> = 18A, Note 1	38		45 mΩ

**Features**

- International Standard Package
- Plastic Overmolded Tab
- Low R<sub>DS(ON)</sub> and Q<sub>G</sub>
- Avalanche Rated
- 2500V~ Electrical Isolation
- Low Package Inductance

**Advantages**

- High Power Density
- Easy to Mount
- Space Savings

**Applications**

- Switch-Mode and Resonant-Mode Power Supplies
- DC-DC Converters
- PFC Circuits
- AC and DC Motor Drives
- Robotics and Servo Controls

Symbol	Test Conditions ( $T_J = 25^\circ\text{C}$ , Unless Otherwise Specified)	Characteristic Values		
		Min.	Typ.	Max
$g_{fs}$	$V_{DS} = 10\text{V}$ , $I_D = 18\text{A}$ , Note 1	16	26	S
$R_{GI}$	Gate Input Resistance		1.6	$\Omega$
$C_{iss}$	$V_{GS} = 0\text{V}$ , $V_{DS} = 25\text{V}$ , $f = 1\text{MHz}$	1425		pF
$C_{oss}$		280		pF
$C_{rss}$		1.2		pF
<b>Effective Output Capacitance</b>				
$C_{o(er)}$	Energy related } $V_{GS} = 0\text{V}$	130		pF
$C_{o(tr)}$	Time related } $V_{DS} = 0.8 \cdot V_{DSS}$	400		pF
$t_{d(on)}$	<b>Resistive Switching Times</b> $V_{GS} = 10\text{V}$ , $V_{DS} = 0.5 \cdot V_{DSS}$ , $I_D = 18\text{A}$ $R_G = 30\Omega$ (External)	19		ns
$t_r$		30		ns
$t_{d(off)}$		54		ns
$t_f$		20		ns
$Q_{g(on)}$	$V_{GS} = 10\text{V}$ , $V_{DS} = 0.5 \cdot V_{DSS}$ , $I_D = 18\text{A}$	21		nC
$Q_{gs}$		8		nC
$Q_{gd}$		7		nC
$R_{thJC}$			3.5 $^\circ\text{C}/\text{W}$	
$R_{thCS}$		0.50		$^\circ\text{C}/\text{W}$

### Source-Drain Diode

Symbol	Test Conditions ( $T_J = 25^\circ\text{C}$ , Unless Otherwise Specified)	Characteristic Values		
		Min.	Typ.	Max
$I_s$	$V_{GS} = 0\text{V}$		36	A
$I_{SM}$	Repetitive, Pulse Width Limited by $T_{JM}$		144	A
$V_{SD}$	$I_F = I_S$ , $V_{GS} = 0\text{V}$ , Note 1		1.4	V
$t_{rr}$	$I_F = 18\text{A}$ , $-di/dt = 100\text{A}/\mu\text{s}$ $V_R = 100\text{V}$	75		ns
$Q_{RM}$		230		nC
$I_{RM}$		6		A

Note 1. Pulse test,  $t \leq 300\mu\text{s}$ , duty cycle,  $d \leq 2\%$ .

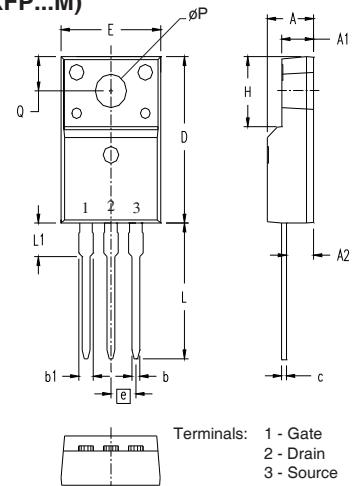
### PRELIMINARY TECHNICAL INFORMATION

The product presented herein is under development. The Technical Specifications offered are derived from a subjective evaluation of the design, based upon prior knowledge and experience, and constitute a "considered reflection" of the anticipated result. IXYS reserves the right to change limits, test conditions, and dimensions without notice.

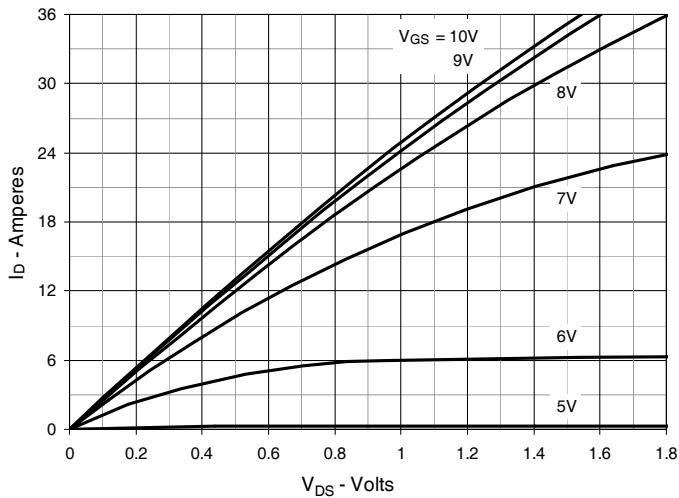
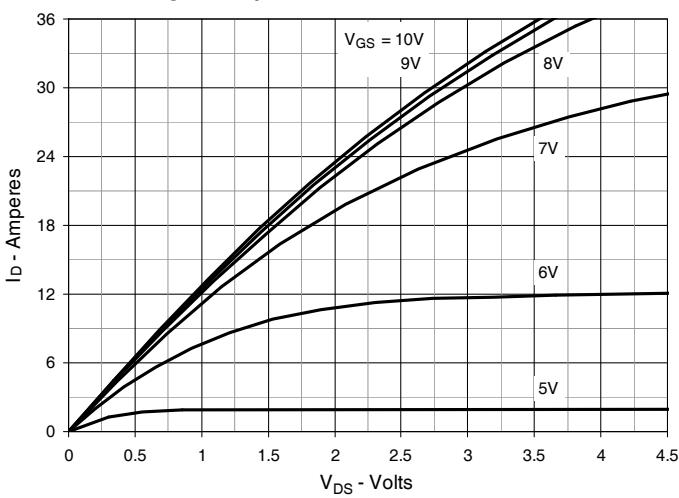
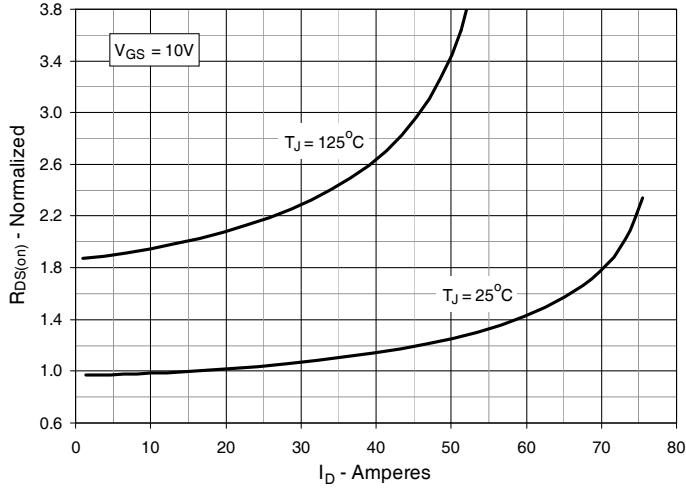
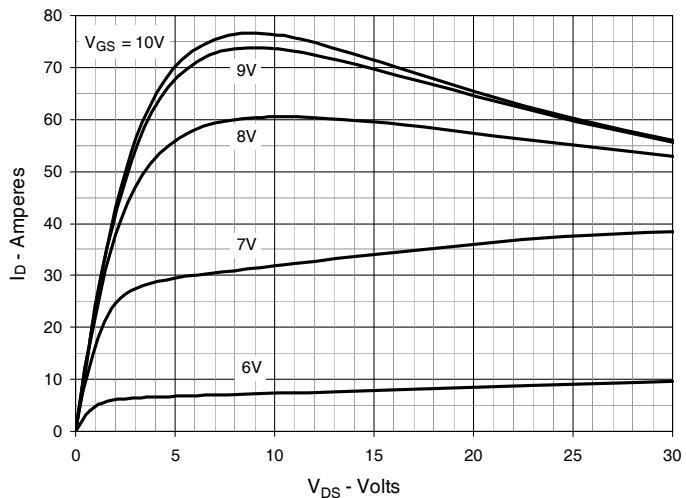
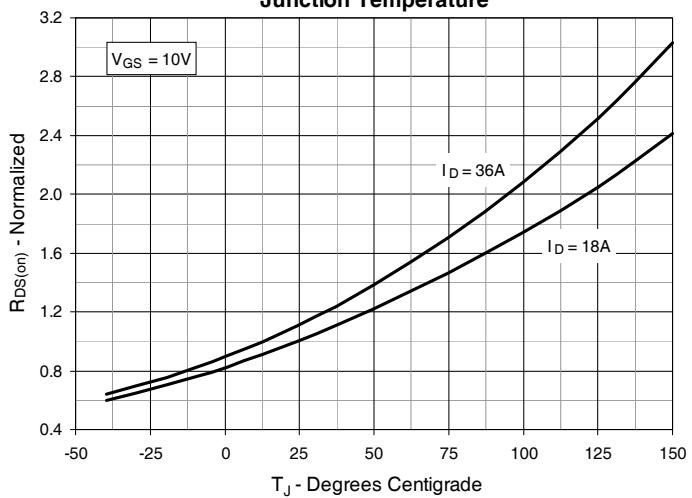
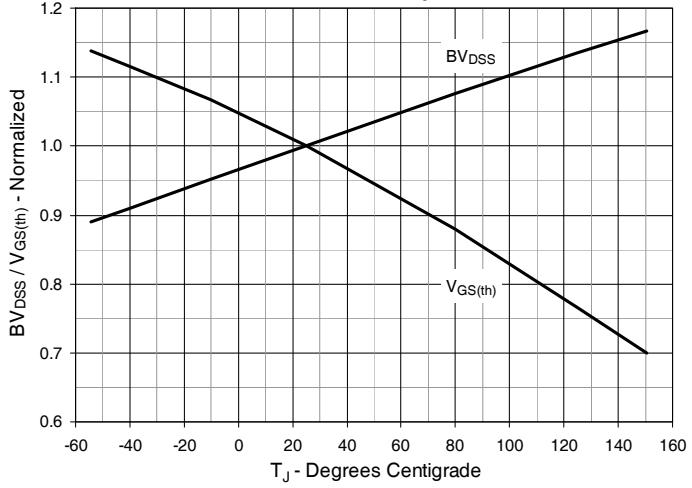
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IXYS MOSFETs and IGBTs are covered by one or more of the following U.S. patents: 4,835,592 4,931,844 5,049,961 5,237,481 6,162,665 6,404,065B1 6,683,344 6,727,585 7,005,734B2 7,157,338B2 4,860,072 5,017,508 5,063,307 5,381,025 6,259,123B1 6,534,343 6,710,405B2 6,759,692 7,063,975B2 4,881,106 5,034,796 5,187,117 5,486,715 6,306,728B1 6,583,505 6,710,463 6,771,478B2 7,071,537

### OVERMOLDED TO-220 (IXFP...M)



SYM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	.177	.193	4.50	4.90
A1	.092	.108	2.34	2.74
A2	.101	.117	2.56	2.96
b	.028	.035	0.70	0.90
b1	.050	.058	1.27	1.47
c	.018	.024	0.45	0.60
D	.617	.633	15.67	16.07
E	.392	.408	9.96	10.36
e	.100 BSC		2.54 BSC	
H	.255	.271	6.48	6.88
L	.499	.523	12.68	13.28
L1	.119	.135	3.03	3.43
$\emptyset P$	.121	.129	3.08	3.28
Q	.126	.134	3.20	3.40

**Fig. 1. Output Characteristics @  $T_J = 25^\circ\text{C}$** **Fig. 3. Output Characteristics @  $T_J = 125^\circ\text{C}$** **Fig. 5.  $R_{DS(on)}$  Normalized to  $I_D = 18\text{A}$  Value vs. Drain Current****Fig. 2. Extended Output Characteristics @  $T_J = 25^\circ\text{C}$** **Fig. 4.  $R_{DS(on)}$  Normalized to  $I_D = 18\text{A}$  Value vs. Junction Temperature****Fig. 6. Normalized Breakdown & Threshold Voltages vs. Junction Temperature**

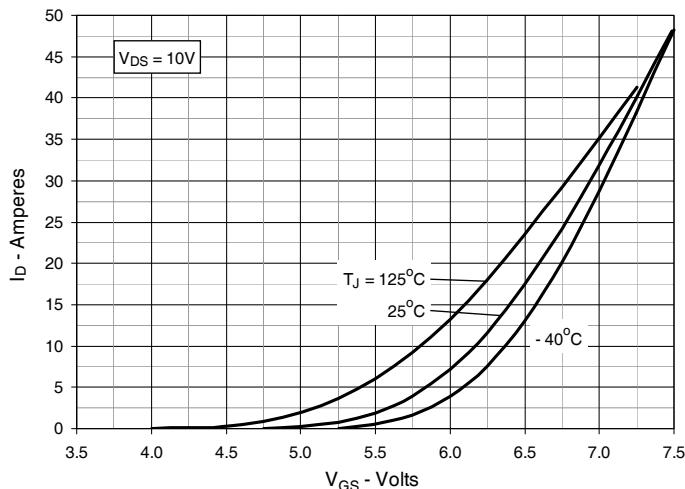
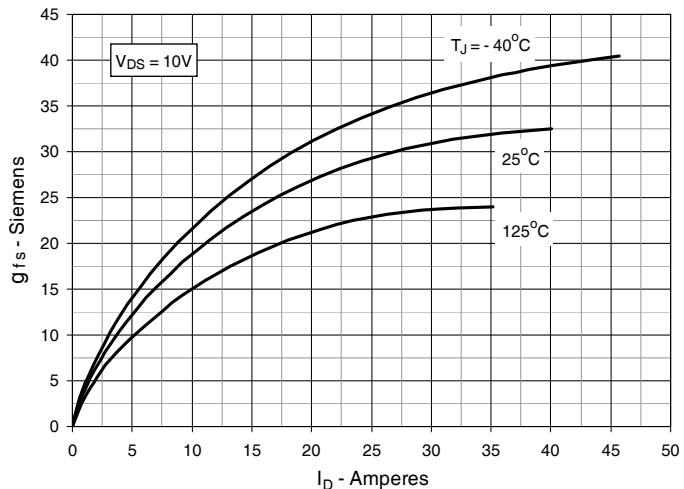
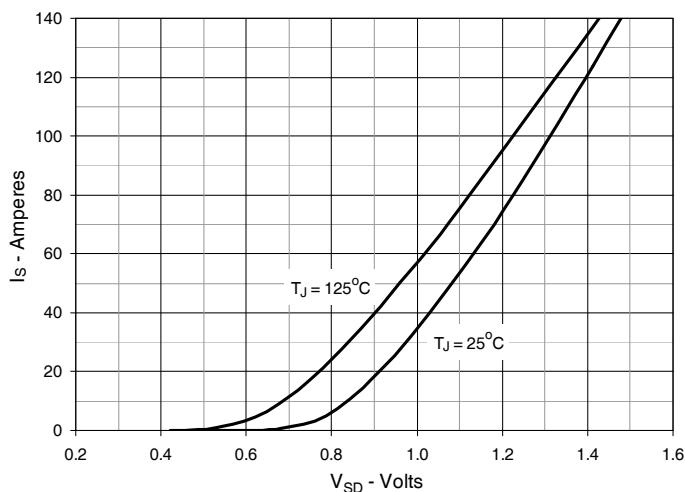
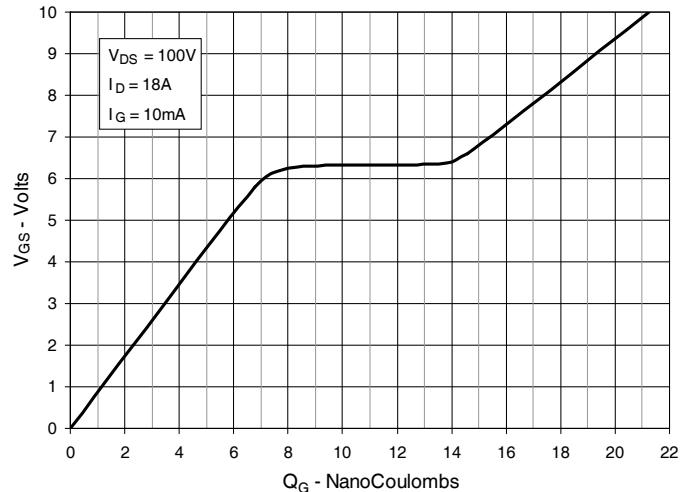
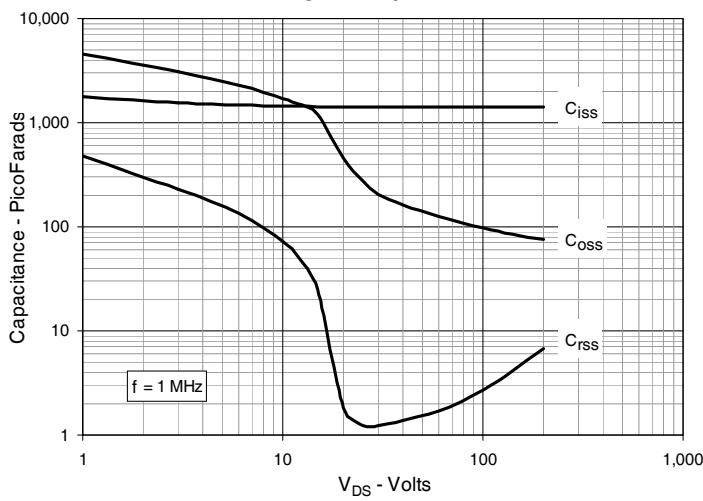
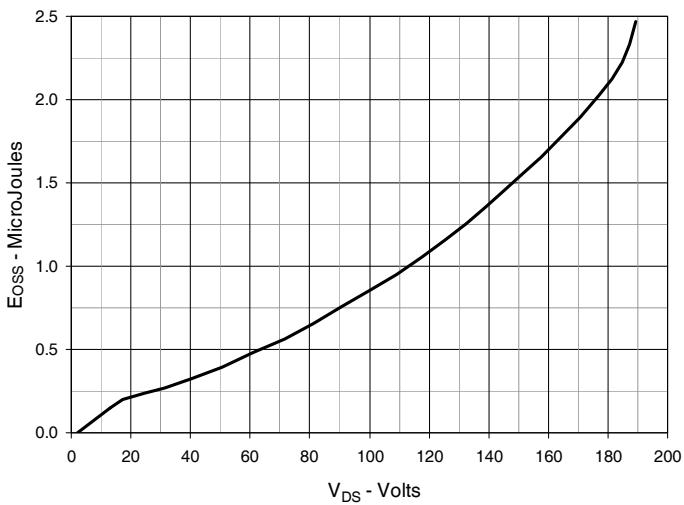
**Fig. 7. Input Admittance**

**Fig. 8. Transconductance**

**Fig. 9. Forward Voltage Drop of Intrinsic Diode**

**Fig. 10. Gate Charge**

**Fig. 11. Capacitance**

**Fig. 12. Output Capacitance Stored Energy**


Fig. 13. Forward-Bias Safe Operating Area

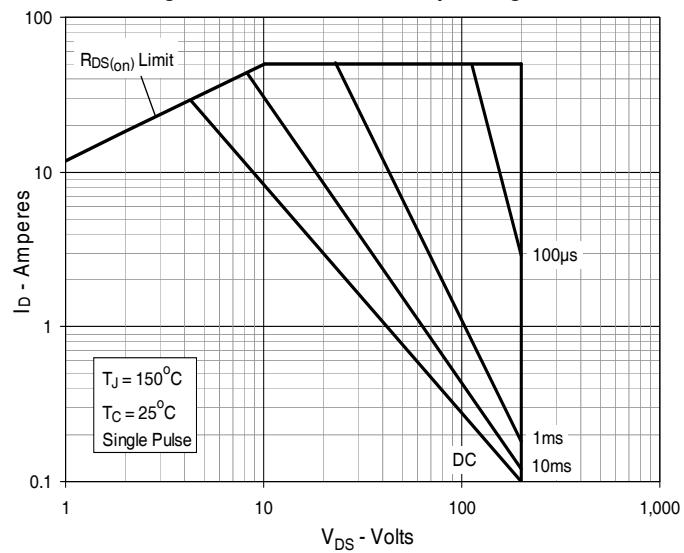
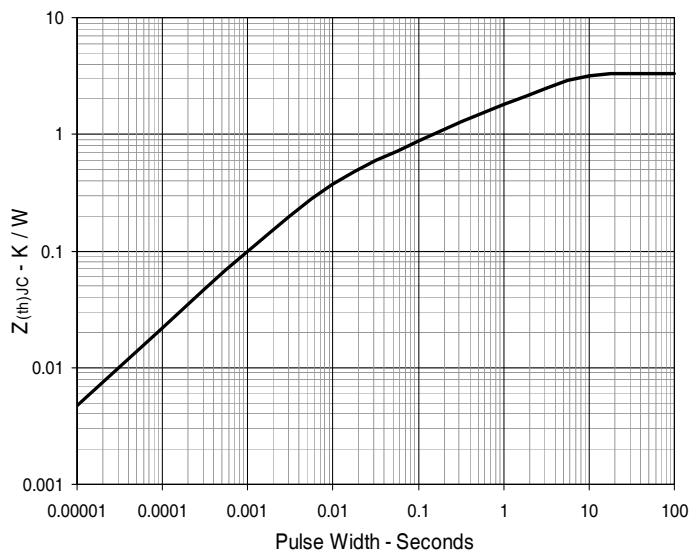


Fig. 14. Maximum Transient Thermal Impedance



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